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Datasheet of BTA310-600D,127 - TRIAC SENS GATE 600V 10A TO220AB Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



Product data sheet

1. General description

Planar passivated high commutation three quadrant triac in a SOT78 (TO-220AB) plastic package. This "series D" triac balances the requirements of commutation performance and gate sensitivity and is intended for interfacing with low power drivers including microcontrollers.

2. Features and benefits

- 3Q technology for improved noise immunity
- · Direct interfacing with low power drivers and microcontrollers
- Good immunity to false turn-on by dV/dt
- High commutation capability with very sensitive gate
- High voltage capability
- Planar passivated for voltage ruggedness and reliability
- Triggering in three quadrants only
- Very sensitive gate for easy logic level triggering

3. Applications

- Electronic thermostats (heating and cooling)
- Motor controls e.g. washing machines and vacuum cleaners
- · Refrigeration and air-conditioner compressor controls

4. Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|--|---|-----|-----|-----|------|
| V_{DRM} | repetitive peak off- state voltage | | - | - | 600 | V |
| I _{TSM} | non-repetitive peak on- state current | full sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 20 \text{ ms}$; Fig. 4; Fig. 5 | - | - | 85 | Α |
| Tj | junction temperature | | - | - | 125 | °C |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 106 ^{\circ}\text{C}$; Fig. 1; Fig. 2; Fig. 3 | - | - | 10 | A |
| Static chara | acteristics | | | | ' | |
| I _{GT} | gate trigger current | $V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ °C}; Fig. 7$ | 0.3 | - | 5 | mA |







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| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|-----|-----|-----|------|
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + \text{ G-;}$ $T_j = 25 \text{ °C; } Fig. 7$ | 0.3 | - | 5 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2-\text{ G-;}$ $T_j = 25 \text{ °C; } Fig. 7$ | 0.3 | - | 5 | mA |
| Dynamic chara | acteristics | | | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit | 20 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 10 A; dV_{com}/dt = 1 V/ μ s; gate open circuit | 4.5 | - | - | A/ms |

5. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|--------------------------------|--------------------|----------------|
| 1 | T1 | main terminal 1 | mb | T2——T1 |
| 2 | T2 | main terminal 2 | 1 7 9 | Sym051 |
| 3 | G | gate | | 3 |
| mb | Т2 | mounting base; main terminal 2 | | |
| | | | TO-220AB (SOT78) | |

6. Ordering information

Table 3. Ordering information

| Type number | Package | kage | | | | |
|-------------|----------|--|---------|--|--|--|
| | Name | Description | Version | | | |
| BTA310-600D | TO-220AB | plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB | SOT78 | | | |

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | M | in | Max | Unit |
|---------------------|--------------------------------------|--|----|----|------|------------------|
| V_{DRM} | repetitive peak off-state voltage | | - | | 600 | V |
| I _{T(RMS)} | RMS on-state current | full sine wave; $T_{mb} \le 106 ^{\circ}\text{C}$; Fig. 1; Fig. 2; Fig. 3 | - | | 10 | A |
| I _{TSM} | non-repetitive peak on-state current | full sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 20 \text{ms}$; Fig. 4; Fig. 5 | - | | 85 | A |
| | | full sine wave; $T_{j(init)} = 25 ^{\circ}C$; $t_p = 16.7 \text{ms}$ | - | | 93 | A |
| I ² t | I ² t for fusing | t _p = 10 ms; SIN | - | | 36.1 | A ² s |
| dl _T /dt | rate of rise of on-state current | $I_T = 20 \text{ A}; I_G = 0.2 \text{ A}; dI_G/dt = 0.2 \text{ A/}\mu\text{s}$ | - | | 100 | A/µs |
| I _{GM} | peak gate current | | - | | 2 | Α |
| P_GM | peak gate power | | - | | 5 | W |
| P _{G(AV)} | average gate power | over any 20 ms period | - | | 0.5 | W |
| T _{stg} | storage temperature | | -4 | 10 | 150 | °C |
| Tj | junction temperature | | - | | 125 | °C |

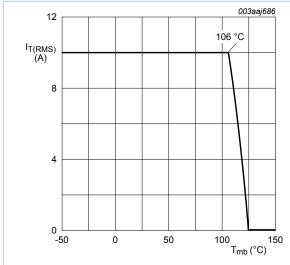


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values

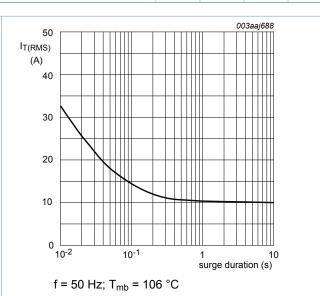


Fig. 2. RMS on-state current as a function of surge duration; maximum values

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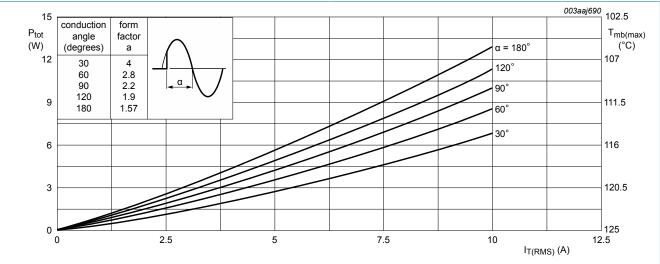
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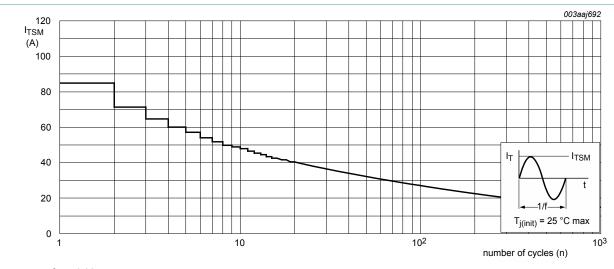
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 α = conduction angle

 $a = form factor = I_{T(RMS)} / I_{T(AV)}$

Fig. 3. Total power dissipation as a function of RMS on-state current; maximum values



f = 50 Hz

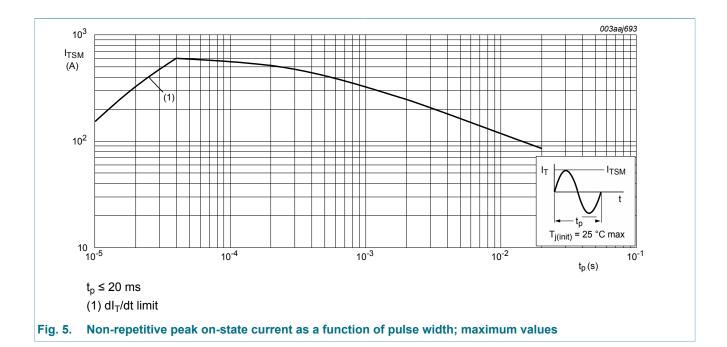
Fig. 4. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

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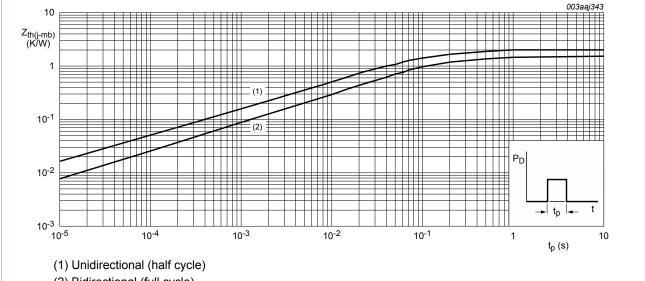
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8. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|--------------------|-----|-----|-----|------|
| R _{th(j-mb)} | thermal resistance | full cycle; Fig. 6 | - | - | 1.5 | K/W |
| | from junction to mounting base | half cycle; Fig. 6 | - | - | 2 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | in free air | - | 60 | - | K/W |



(2) Bidirectional (full cycle)

Fig. 6. Transient thermal impedance from junction to mounting base as a function of pulse duration



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9. Characteristics

Table 6. Characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---------------------------------------|--|------|------|-----|------|
| Static chara | acteristics | | · | | | |
| I _{GT} | gate trigger current | V _D = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u> | 0.3 | - | 5 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2 + \text{ G-;}$ $T_j = 25 \text{ °C; } \underline{\text{Fig. 7}}$ | 0.3 | - | 5 | mA |
| | | $V_D = 12 \text{ V; } I_T = 0.1 \text{ A; } T2\text{- G-;}$ $T_j = 25 \text{ °C; } \underline{Fig. 7}$ | 0.3 | - | 5 | mA |
| IL | latching current | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G+;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | - | 10 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; T2+ G-;$ $T_j = 25 \text{ °C}; Fig. 8$ | - | - | 15 | mA |
| | | $V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \underline{\text{Fig. 8}}$ | - | - | 15 | mA |
| I _H | holding current | V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u> | - | - | 10 | mA |
| V _T | on-state voltage | I _T = 12 A; T _j = 25 °C; <u>Fig. 10</u> | - | 1.25 | 1.5 | V |
| V _{GT} | gate trigger voltage | V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; Fig. 11 | - | 0.7 | 1 | V |
| | | V _D = 400 V; I _T = 0.1 A; T _j = 125 °C; Fig. 11 | 0.25 | 0.4 | - | V |
| I _D | off-state current | V _D = 600 V; T _j = 125 °C | - | 0.1 | 0.5 | mA |
| Dynamic cl | naracteristics | | ' | | | |
| dV _D /dt | rate of rise of off-state voltage | V_{DM} = 402 V; T_j = 125 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit | 20 | - | - | V/µs |
| dl _{com} /dt | rate of change of commutating current | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 10 A; dV_{com}/dt = 20 V/ μ s; (snubberless condition); gate open circuit | 1 | - | - | A/ms |
| | | V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 10 A; dV_{com}/dt = 10 V/ μ s; gate open circuit | 1.5 | - | - | A/ms |
| | | $V_D = 400 \text{ V}; T_j = 125 \text{ °C}; I_{T(RMS)} = 10 \text{ A};$ $dV_{com}/dt = 1 \text{ V/}\mu\text{s}; gate open circuit}$ | 4.5 | - | - | A/ms |

3

2

-50

I_{L(25°C)}



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(3) T2+ G-

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003aaj695

100 _{Ti} (°C) 150

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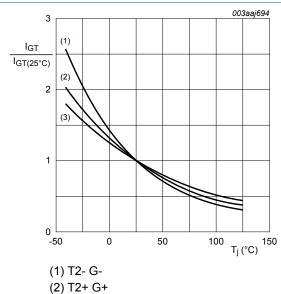


Fig. 8. Normalized latching current as a function of junction temperature



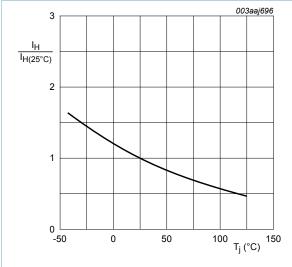
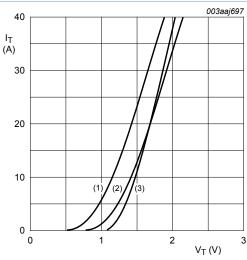


Fig. 9. Normalized holding current as a function of junction temperature



 $V_0 = 1.103 \text{ V}; R_s = 0.030 \Omega$

(1) T_i = 125 °C; typical values

(2) T_i = 125 °C; maximum values

(3) T_i = 25 °C; maximum values

Fig. 10. On-state current as a function of on-state voltage

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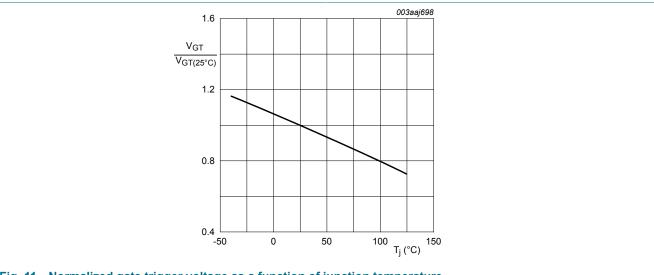


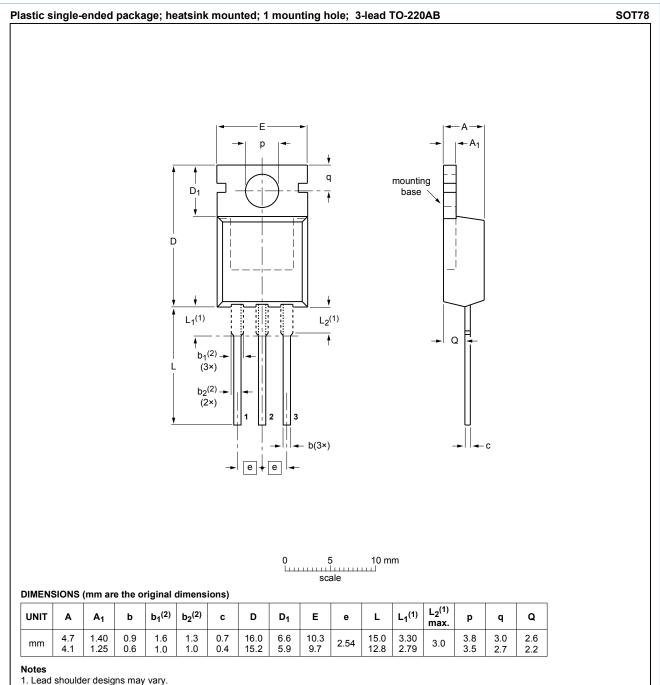
Fig. 11. Normalized gate trigger voltage as a function of junction temperature



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10. Package outline



- 2. Dimension includes excess dambar.

| OUTLINE | | REFER | ENCES | EUROPEAN | ISSUE DATE |
|---------|-----|-----------------|-------|------------|---------------------------------|
| VERSION | IEC | JEDEC | JEITA | PROJECTION | ISSUE DATE |
| SOT78 | | 3-lead TO-220AB | SC-46 | | 08-04-23 08-06-13 |

Fig. 12. Package outline TO-220AB (SOT78)

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